Low-ohmic single-pole single-throw analog switch

Rev. 3.1 — 17 October 2016

**Product data sheet** 

## 1. General description

The NX3L1T384 is a low-ohmic single-pole single-throw analog switch. It has two input/output terminals (Y and Z) and an active LOW enable input pin ( $\overline{E}$ ). When  $\overline{E}$  is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input  $(\overline{E})$  makes the circuit tolerant to slower input rise and fall times. A low input voltage threshold allows pin  $\overline{E}$  to be driven by lower level logic signals without a significant increase in supply current I<sub>C C</sub>. This makes it possible for the NX3L1T384 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3L1T384 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from Y to Z; or from Z to Y. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

## 2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.6  $\Omega$  (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0  $\Omega$  (typical) at V<sub>CC</sub> = 1.65 V
  - 0.55  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 4000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78B Class II Level A
- 1.8 V control logic at V<sub>CC</sub> = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V<sub>CC</sub>
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Low-ohmic single-pole single-throw analog switch

## 3. Applications

- Cell phone
- PDA
- Portable media player

# 4. Ordering information

Table 1.	Ordering information
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Type number	Package								
	Temperature range	Name	Description	Version					
NX3L1T384GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886					

## 5. Marking

#### Table 2. Marking codes<sup>[1]</sup>

Type number	Marking code
NX3L1T384GM	M3

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

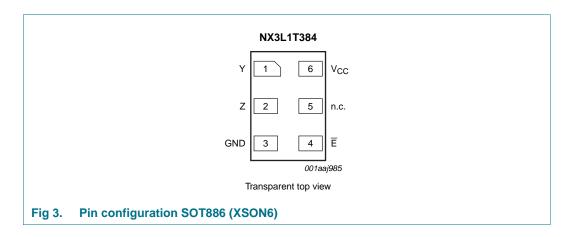
## 6. Functional diagram



Low-ohmic single-pole single-throw analog switch

## 7. Pinning information

## 7.1 Pinning



## 7.2 Pin description

#### Table 3. Pin description

Symbol	Pin	Description			
Y	1	independent input or output			
Z	2	independent output or input			
GND	3	ground (0 V)			
Ē	4	enable input (active LOW)			
n.c.	5	not connected			
V <sub>CC</sub>	6	supply voltage			

# 8. Functional description

#### Table 4.Function table[1]

Input E	Switch
L	ON-state
Н	OFF-state

[1] H = HIGH voltage level; L = LOW voltage level.

Low-ohmic single-pole single-throw analog switch

## 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	enable input E	l –0.5	+4.6	V
V <sub>SW</sub>	switch voltage	[2	l –0.5	V <sub>CC</sub> + 0.5	V
l <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{I}$ < -0.5 V or $V_{I}$ > $V_{CC}$ + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current	-	±350	mA
		$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C} $	l -	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For TSSOP5 package: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 10. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.4	4.3	V
VI	input voltage	enable input E	0	4.3	V
V <sub>SW</sub>	switch voltage	[1]	0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$ [2]	-	200	ns/V

[1] To avoid sinking GND current from of terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

Low-ohmic single-pole single-throw analog switch

# **11. Static characteristics**

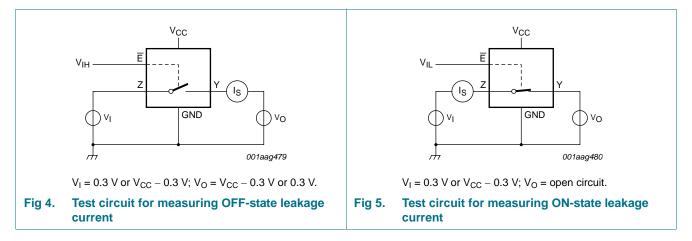
### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
VIH	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I	input leakage current	enable input $\overline{E}$ ; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state	Y port; see Figure 4							-
	leakage	V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state	Z port; see Figure 5							-
	leakage current	V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							-
		V <sub>CC</sub> = 3.6 V	-	-	100	-	690	6000	nA
		V <sub>CC</sub> = 4.3 V	-	-	150	-	800	7000	nA
$\Delta I_{CC}$	additional	$V_{SW}$ = GND or $V_{CC}$							
	supply current	V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 4.3 V	-	2.0	4.0	-	7	7	μA
		V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 3.6 V	-	0.35	0.7	-	1	1	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 4.3 V	-	7.0	10.0	-	15	15	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 3.6 V	-	2.5	4.0	-	5	5	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 2.5 V	-	50	200	-	300	500	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	110	-	-	-	-	pF

Low-ohmic single-pole single-throw analog switch

## 11.1 Test circuits



### 11.2 ON resistance

#### Table 8.ON resistance

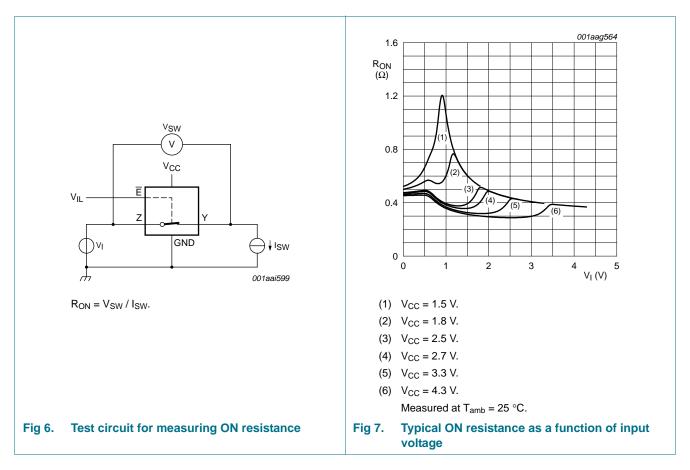
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

Symbol	Parameter	Conditions	T <sub>amb</sub> =	-40 °C to	• +85 °C	T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND$ to $V_{CC}$ ; $I_{SW} = 100$ mA; see Figure 6						
		V <sub>CC</sub> = 1.4 V	-	1.6	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	$V_{I} = GND \text{ to } V_{CC}; \qquad [2] \\ I_{SW} = 100 \text{ mA}$						
		V <sub>CC</sub> = 1.4 V	-	1.0	3.3	-	3.6	Ω
		V <sub>CC</sub> = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		V <sub>CC</sub> = 2.7 V	-	0.13	0.3	-	0.35	Ω
		V <sub>CC</sub> = 4.3 V	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ .

[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

Low-ohmic single-pole single-throw analog switch

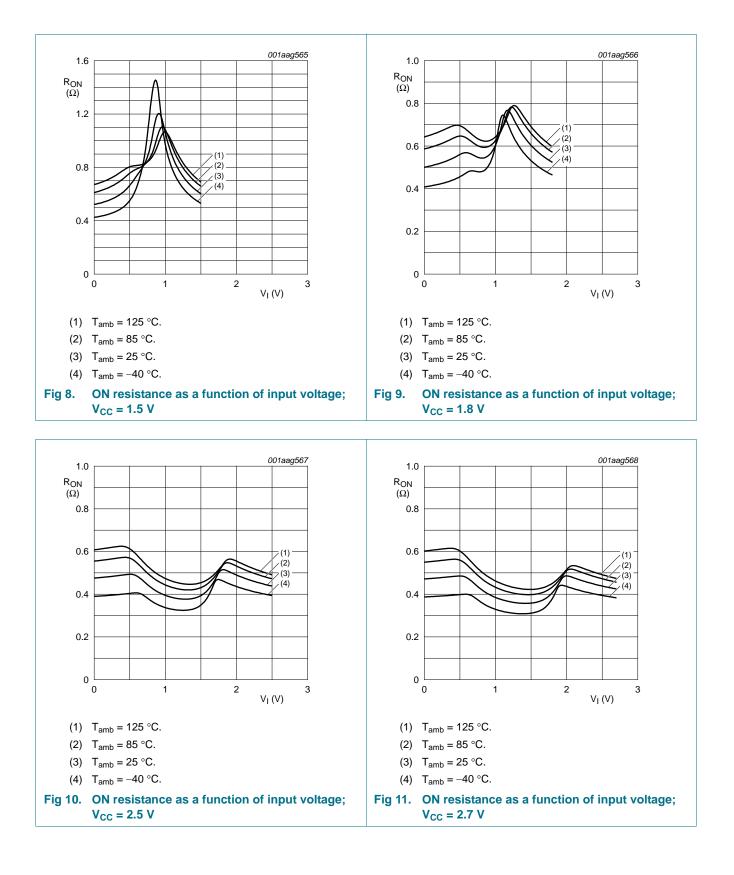


## 11.3 ON resistance test circuit and graphs

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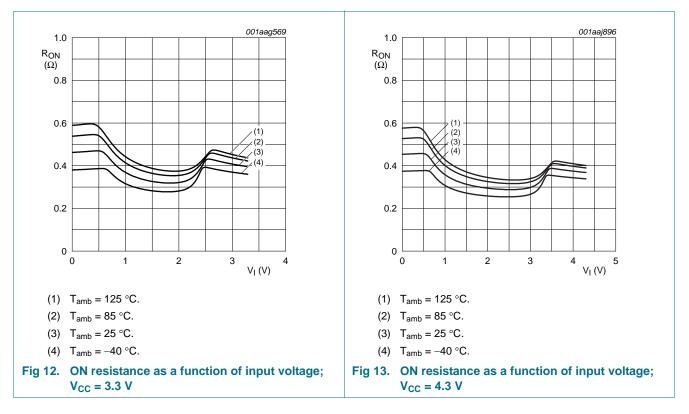
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Low-ohmic single-pole single-throw analog switch



## **12. Dynamic characteristics**

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 15.

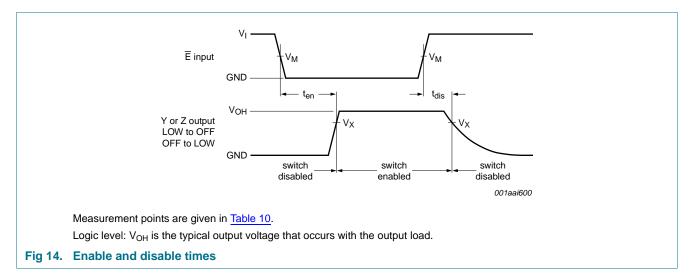
Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +125 °C			Unit	
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	E to Z or Y; see Figure 14							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	50	90	-	120	120	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	-	36	70	-	80	90	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	24	45	-	50	55	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	22	40	-	45	50	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	22	40	-	45	50	ns
t <sub>dis</sub>	disable time	E to Z or Y; see Figure 14							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	30	45	-	50	60	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	20	30	-	35	40	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	15	20	-	22	25	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	11	15	-	18	22	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	11	15	-	18	22	ns

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

NX3L1T384 Product data sheet

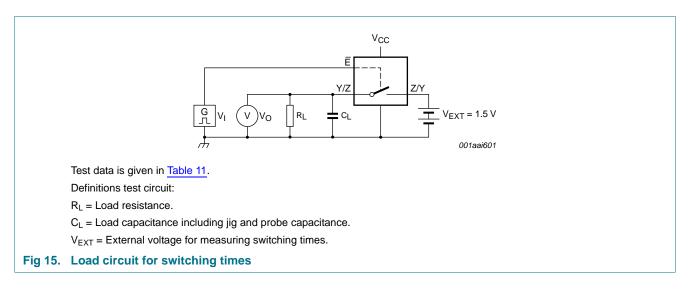
Low-ohmic single-pole single-throw analog switch

## 12.1 Waveform and test circuits



#### Table 10.Measurement points

Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>



#### Table 11. Test data

Supply voltage	Input		Load	
V <sub>cc</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL
1.4 V to 4.3 V	V <sub>CC</sub>	≤ 2.5 ns	35 pF	50 Ω

NX3L1T384 Product data sheet

Low-ohmic single-pole single-throw analog switch

## 12.2 Additional dynamic characteristics

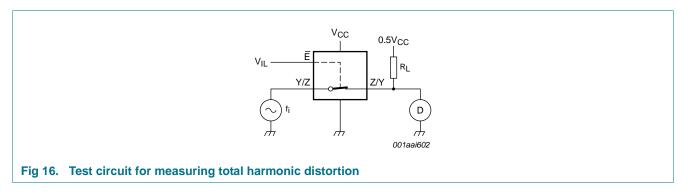
#### Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns.

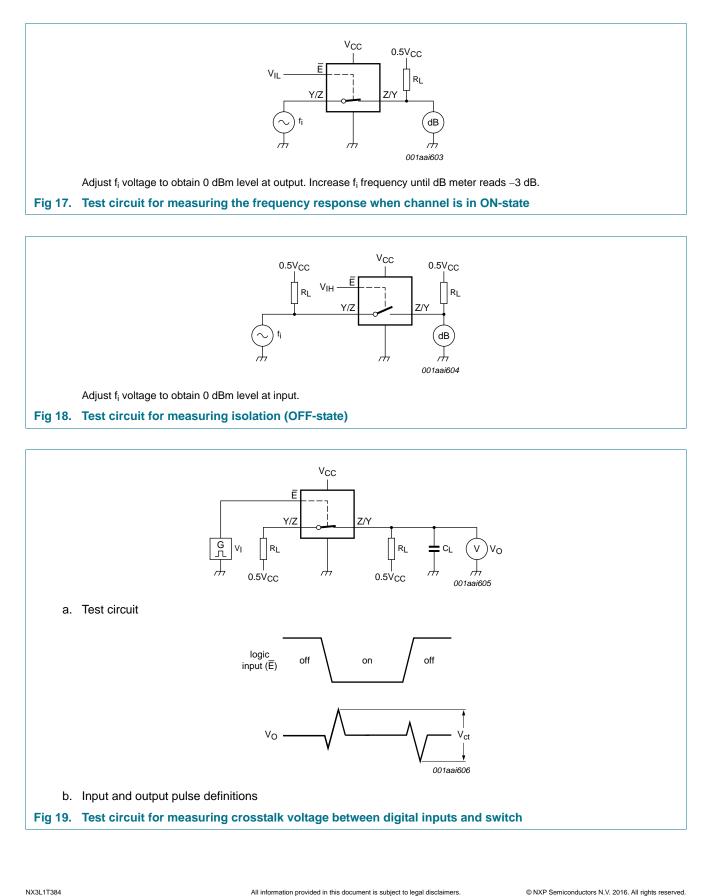
Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C			Unit
				Min	Тур	Max	
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$ ; see Figure 16	<u>[1]</u>				
		V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)		-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)		-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
f <sub>(-3dB)</sub>	-3 dB frequency response	$R_L = 50 \Omega$ ; see Figure 17	<u>[1]</u>				
		V <sub>CC</sub> = 1.4 V to 4.3 V		-	60	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 18}}{100 \text{ kHz}}$	<u>[1]</u>				
		V <sub>CC</sub> = 1.4 V to 4.3 V		-	-90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 19					
		V <sub>CC</sub> = 1.4 V to 3.6 V		-	0.2	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V		-	0.2	-	V
Q <sub>inj</sub>	charge injection	$      f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 20}}{1000}        $					
		V <sub>CC</sub> = 1.5 V		-	3	-	рС
		V <sub>CC</sub> = 1.8 V		-	3	-	рС
		V <sub>CC</sub> = 2.5 V		-	3	-	рС
		V <sub>CC</sub> = 3.3 V		-	3	-	рС
		V <sub>CC</sub> = 4.3 V		-	6	-	рС

[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

### 12.3 Test circuits



Low-ohmic single-pole single-throw analog switch

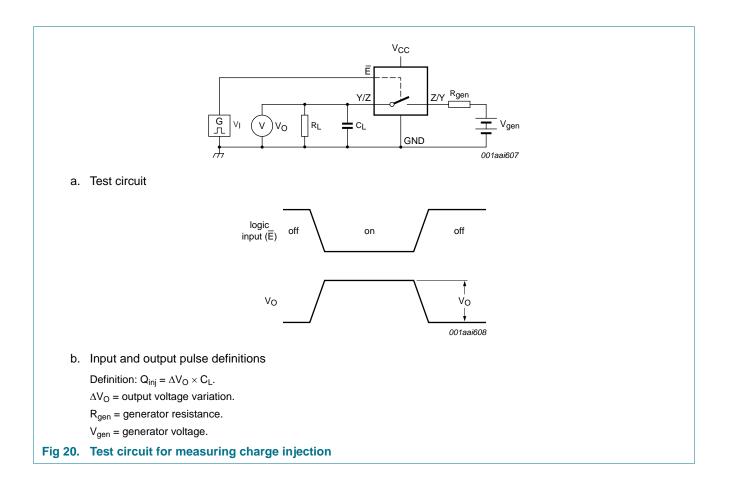


12 of 18

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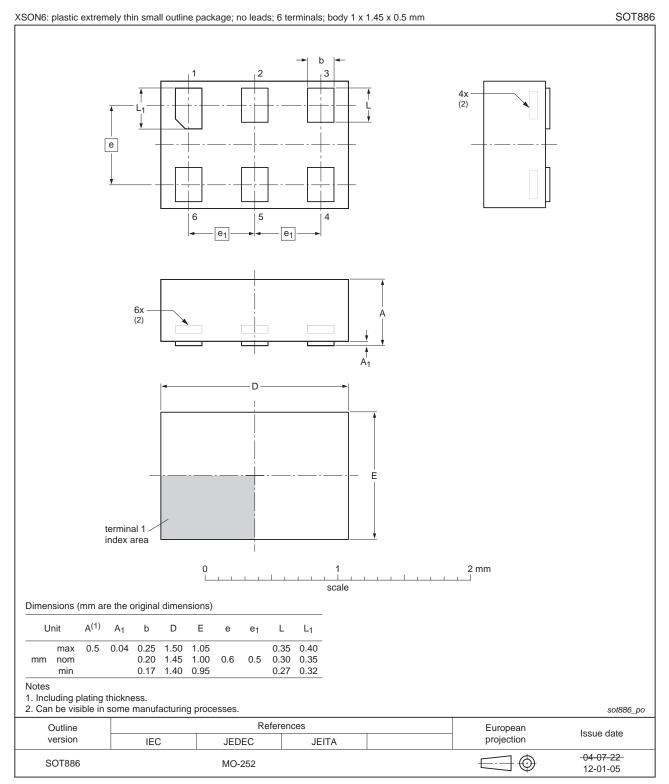
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### Low-ohmic single-pole single-throw analog switch



#### Low-ohmic single-pole single-throw analog switch

## 13. Package outline



### Fig 21. Package outline SOT886 (XSON6)

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NX3L1T384

14 of 18

Low-ohmic single-pole single-throw analog switch

# 14. Abbreviations

Table 13. Abbreviations		
Acronym	Description	
CDM	Charged-Device Model	
CMOS	Complementary Metal-Oxide Semiconductor	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	
PDA	Personal Digital Assistant	

# 15. Revision history

### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
NX3L1T384 v.3.1	20161017	Product data sheet	-	NX3L1T384 v.3		
Modifications:	Removed	Removed NX3L1T384GW				
NX3L1T384 v.3	20111109	Product data sheet	-	NX3L1T384 v.2		
Modifications:	<ul> <li>Legal page</li> </ul>	es updated	I			
NX3L1T384 v.2	20110107	Product data sheet	-	NX3L1T384 v.1		
NX3L1T384 v.1	20090929	Product data sheet	-	-		

Low-ohmic single-pole single-throw analog switch

## 16. Legal information

### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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#### Low-ohmic single-pole single-throw analog switch

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## **18. Contents**

1	General description 1
2	Features and benefits 1
3	Applications 2
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information 3
7.1	Pinning
7.2	Pin description 3
8	Functional description 3
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Test circuits 6
11.2	ON resistance 6
11.3	ON resistance test circuit and graphs7
12	Dynamic characteristics 9
12.1	Waveform and test circuits 10
12.2	Additional dynamic characteristics 11
12.3	Test circuits 11
13	Package outline 14
14	Abbreviations 15
15	Revision history 15
16	Legal information 16
16.1	Data sheet status 16
16.2	Definitions 16
16.3	Disclaimers 16
16.4	Trademarks
17	Contact information 17
18	Contents 18

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### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж: moschip.ru moschip.ru\_4

moschip.ru\_6 moschip.ru\_9